# MOS FIELD EFFECT TRANSISTOR $\mu PA2451C$

# N-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

# DESCRIPTION

NEC

The  $\mu$  PA2451C is a switching device, which can be driven directly by a 2.5 V power source.

The  $\mu$  PA2451C features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

### FEATURES

- 2.5 V drive available
- · Low on-state resistance
- $\begin{array}{l} {R_{DS(on)1}=20.0\ m\Omega\ MAX.\ (V_{GS}=4.5\ V,\ I_{D}=4.0\ A)} \\ {R_{DS(on)2}=21.0\ m\Omega\ MAX.\ (V_{GS}=4.0\ V,\ I_{D}=4.0\ A)} \\ {R_{DS(on)3}=25.0\ m\Omega\ MAX.\ (V_{GS}=3.1\ V,\ I_{D}=4.0\ A)} \\ {R_{DS(on)4}=32.0\ m\Omega\ MAX.\ (V_{GS}=2.5\ V,\ I_{D}=4.0\ A)} \end{array}$
- Built-in G-S protection diode against ESD

### ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

VDSS	30.0	V
Vgss	±12.0	V
D(DC)	±8.2	Α
D(pulse)	±60.0	А
Pt1	2.5	W
Pt2	0.7	W
Tch	150	°C
Tstg	-55 to +150	°C
	VGSS ID(DC) ID(pulse) PT1 PT2 Tch	VGSS ±12.0   ID(DC) ±8.2   ID(pulse) ±60.0   PT1 2.5   PT2 0.7   Tch 150

Notes 1. Mounted on ceramic board of 50 cm<sup>2</sup> x 1.1 mmt

- **2.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1%
- 3. Mounted on FR-4 board of 50 cm<sup>2</sup> x 1.1 mmt

# ORDERING INFORMATION

PART NUMBER	LEAD PLATING PACKING		PACKAGE						
μ PA2451CTL-E1-A <sup>Note</sup>		Reel							
$\mu$ PA2451CTL-E2-A <sup>Note</sup>	Sn-Bi	3000 p/reel	6PIN HWSON (4521)						

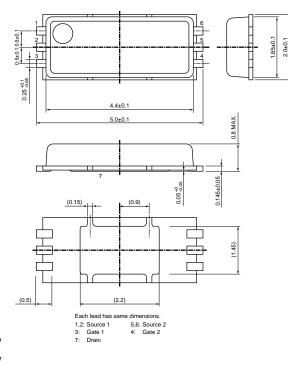
Note Pb-free (This product does not contain Pb in the external electrode and other parts.)

**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

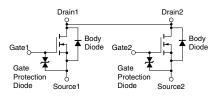
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# PACKAGE DRAWING (Unit: mm)



# EQUIVALENT CIRCUIT

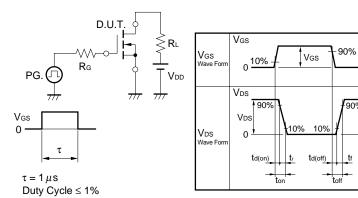


CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> = 30.0 V, V <sub>GS</sub> = 0 V			1.0	μA
Gate Leakage Current	lgss	V <sub>GS</sub> = ±12.0 V, V <sub>DS</sub> = 0 V			±10.0	μA
Gate to Source Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 10.0 V, I <sub>D</sub> = 1.0 mA	0.50		1.50	V
Forward Transfer Admittance Note	y <sub>fs</sub>	V <sub>DS</sub> = 10.0 V, I <sub>D</sub> = 4.0 A	6.0			S
Drain to Source On-state Resistance <sup>Note</sup>	RDS(on)1	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 4.0 A	12.0	17.5	20.0	mΩ
	RDS(on)2	V <sub>GS</sub> = 4.0 V, I <sub>D</sub> = 4.0 A	12.5	18.0	21.0	mΩ
	RDS(on)3	V <sub>GS</sub> = 3.1 V, I <sub>D</sub> = 4.0 A	14.0	21.0	25.0	mΩ
	RDS(on)4	V <sub>GS</sub> = 2.5 V, I <sub>D</sub> = 4.0 A	15.5	25.5	32.0	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> = 10.0 V,		605		pF
Output Capacitance	Coss	V <sub>GS</sub> = 0 V,		87		pF
Reverse Transfer Capacitance	Crss	f = 1.0 MHz		40		pF
Turn-on Delay Time	td(on)	V <sub>DD</sub> = 15.0 V,		40		ns
Rise Time	tr	I <sub>D</sub> = 4.0 A,		75		ns
Turn-off Delay Time	td(off)	V <sub>GS</sub> = 4.0 V,		140		ns
Fall Time	tr	R <sub>G</sub> = 6 Ω		85		ns
Total Gate Charge	QG	V <sub>DD</sub> = 24.0 V,		6.3		nC
Gate to Source Charge	Q <sub>GS</sub>	V <sub>GS</sub> = 4.0 V,		1.5		nC
Gate to Drain Charge	Qgd	I <sub>D</sub> = 8.2 A		2.3		nC
Body Diode Forward Voltage Note	VF(S-D)	IF = 8.2 A, VGS = 0 V		0.86		V

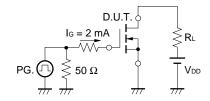
# ELECTRICAL CHARACTERISTICS (TA = 25°C)

**Note** Pulsed: PW  $\leq$  350  $\mu$ s, Duty Cycle  $\leq$  2%

# **TEST CIRCUIT 1 SWITCHING TIME**

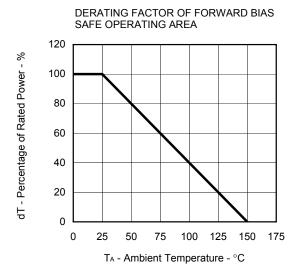


# TEST CIRCUIT 2 GATE CHARGE

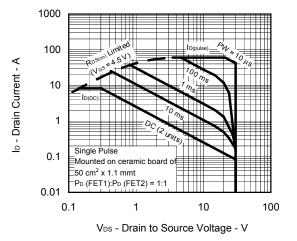


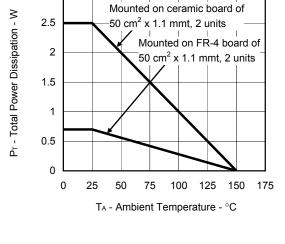
90%

# ELECTRICAL CHARACTERISTICS (TA = 25°C)







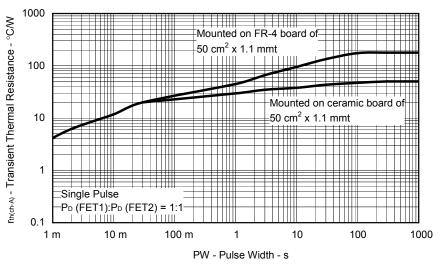


TOTAL POWER DISSIPATION vs.

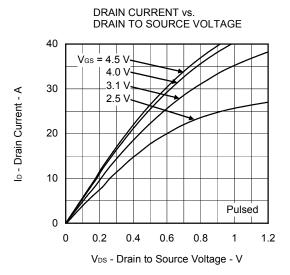
AMBIENT TEMPERATURE

3

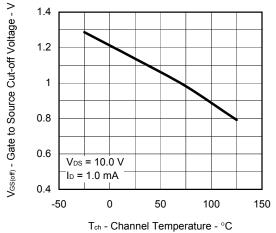
### TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



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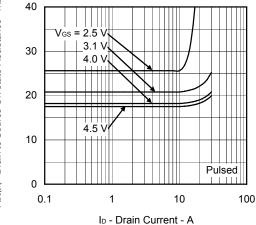




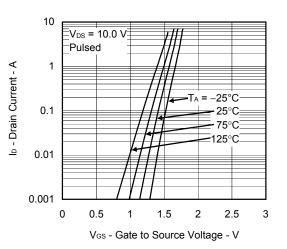




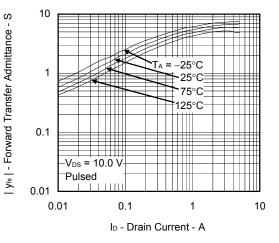




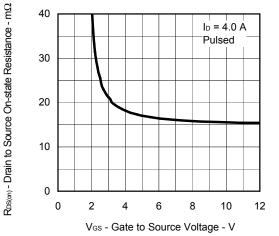
FORWARD TRANSFER CHARACTERISTICS

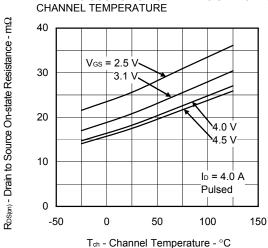


FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



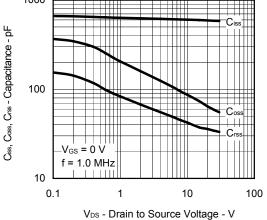
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE





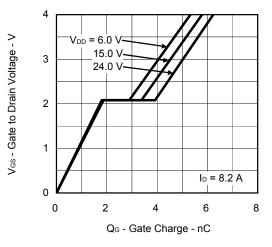
DRAIN TO SOURCE ON-STATE RESISTANCE vs.

CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE

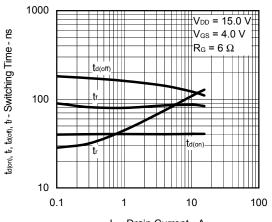


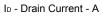
1000

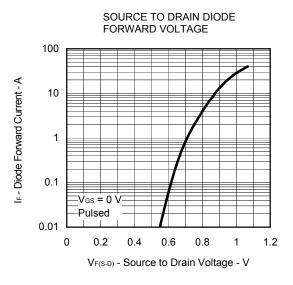
DYNAMIC INPUT CHARACTERISTICS









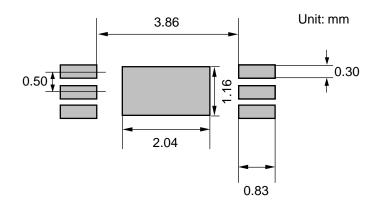


Data Sheet G18793EJ1V0DS

## <Notes for using this device safely>

When you use this device, in order to prevent a customer's hazard and damage, use it with understanding the following contents. If used exceeding recommended conditions, there is a possibility of causing failure of the device and characteristic degradation.

- 1. When you mount the device on a substrate, carry out within our recommended soldering conditions of infrared reflow. If mounted exceeding the conditions, the characteristic of a device may be degraded and it may result in failure.
- 2. When you wash the device mounted the substrate, carry out within our recommended conditions. If washed exceeding the conditions, the characteristic of a device may be degraded and it may result in failure.
- 3. When you use ultrasonic wave to substrate after the device mounting, prevent from touching a resonance generator directly. If it touches, the characteristic of a device may be degraded and it may result in failure.
- 4. Please refer to **Figure 1** as an example of the land pattern. Optimize the land pattern in consideration of density, appearance of solder fillets, common difference, etc in an actual design.



### Figure 1. Example of the land pattern

- NEC
  - 5. This device is very thin device and should be handled with caution for mechanical stress. The rate of distortion applied to the device should become below 2000  $\mu\epsilon$ .<sup>Note1</sup> If the rate of distortion exceeds 2000  $\mu\epsilon$ , the characteristic of a device may be degraded and it may result in failure.

### Figure 2. Direction of substrate and stress

The substrate that mounted the device is on a stand with a support width of 24 mm. The device is turned downward. The stress is applied from a top.

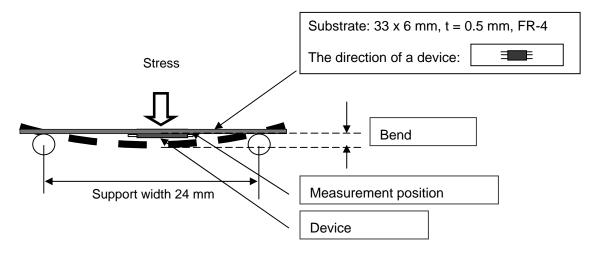
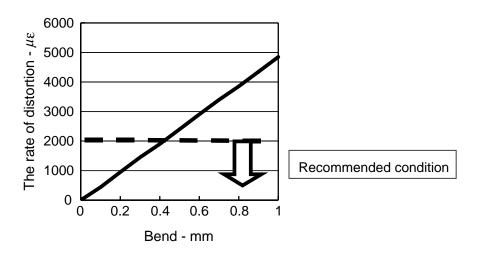
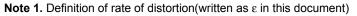


Figure 3. Example of the bend and the rate of distortion Note2





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\epsilon = (I - I_0)/I_0
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- lo: Distance for two arbitrary points before receiving stress.
- I: Distance above-mentioned when receiving stress.
- 2. The relation of the distortion and the bend changes with several conditions, such as a size of substrate and so on.

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